

regime at low and high levels of doping. At low doping levels the glue becomes inactive because of a broken symmetry instability state that blocks superconductivity, while at high doping levels the glue "fades away," the researchers said.

"The reason that superconductivity could not advance above low $T_{\rm c}$ in the past was not because there were no strong coupling constants," Ashkenazi said. Strong coupling due to phonons, and non-phononic magnetic excitations, or other excitations, do exist. "But the system could not progress to very high $T_{\rm c}$ because of the competing symmetry-breaking instabilities, which would kill it."

The researchers suggested a phase diagram by plotting the absolute temperature T versus the hole-doping concentration p for the cuprate system. If pairing is suppressed down to T = 0, a quantum critical point p_c defines the starting point for a quantum phase transition. In the absence of pairing, the quantum critical regime starts at this point and includes the area between the dotted lines in the figure, representing extensions of the Fermi liquid phase and the pseudogap phase of the system. The occurrence of pairing extends the range of quantum criticality into the superconductivity and pseudogap regimes.

As far as what this discovery might mean to experimentalists, Ashkenazi said, "I think this work is an important breakthrough toward a more focused way to give instruction to experimentalists to look for where to go to find high $T_{\rm c}$ superconductors and, hopefully, maybe even room-temperature superconductors. In general you have to look close to phase transitions—in particular, the proximity of a metal–insulator Mott transition is a good place to look for higher $T_{\rm c}$ materials—but our work sets the stage for more work to be done."

Tim Palucka

Nano Focus

Defects in carbon nanotubes heal themselves under the right conditions

Tollowing reports on the experimental growth of carbon nanotubes up to one meter in length, computational simulations have now shown why this is possible. Using density functional theory (DFT) calculations of the energy landscape and the kinetics of carbon nanotube growth, researchers at Hong Kong Polytechnic University, Rice University in Houston, and Tsinghua University have shown that "healing" mechanisms exist at the carbon/catalyst interface that heal and restore potential topological defects-pentagons, heptagons, and pentagon-heptagon (5|7) pairs—to hexagons before they move more than an atomic layer or two beyond the interface.

"In our theoretical analysis we show that at practical temperatures and given the values of energy barriers, the rates of formation and removal of defects are balanced," said Boris Yakobson of Rice University. "They form with some probability and then at a higher rate they are deleted or 'healed.""

According to Feng Ding from Hong Kong Polytechnic University, this finding, reported in the June 15 issue of *Physical Review Letters* (DOI: 10.1103/PhysRevLett.108.245505; 245505), puts to rest the theory that nanotubes form

initially with lots of defects, which are then annealed out at elevated temperatures over time. In fact, any defect that makes it beyond a couple of atomic layers from the interface without being healed is permanently embedded in the carbon structure, leading to nano-cones, nano-horns, or other defective shapes.

Such defective shapes are undesirable for carbon nanotubes intended for use in practical devices because defects change the chiral indices, which are related to the circumference, of the nanotube along its length. The chiral indices define the electronic structure and bandgap of the material, which must be well controlled to define the properties of a nanotube. The ideal is to fabricate perfect nanotubes with the same chiral indices. "The moment you change the chiral index in a tube, you change from one material to another," Yakobson said. "It may change from a metal to a semiconductor the moment you introduce one 5|7 defect."

For these simulations, the researchers abandoned the molecular dynamics approach, which Yakobson said forces calculations to be done too fast for this type of study, producing too many defects along the way. Instead, they decided to slow down the simulation and use DFT for a carbon/Fe catalyst system to calculate and carefully analyze the energy barriers in the system. They followed the changes in atomic positions and calculated the rates of change. Next, they

applied kinetic rate theories to evaluate how often defects are formed and how rapidly they are healed.

The researchers concluded that by controlling the temperature and the rate of carbon introduction to the catalyst, sustained, defect-free nanotube growth would be possible in the range of 10⁸–10¹¹ carbon atoms, setting an upper limit of about one meter on the length of these perfect nanotubes. "Our work shows that defects should not be there to begin with, except in the first one or two atomic rows, but not deeper," Yakobson said. "If you nucleate one tube, it can grow for a very long time and preserve the same chirality."

But can the researchers choose and control the chirality of the carbon nanotube from the nucleation of the first atomic layer at the catalyst surface? Whether the nanotube has a zigzag or an armchair configuration is determined at this crucial moment. "One of the big problems is that nanotubes grow mixed," Yakobson said. "You have a bucket with billions of nanotubes and each is a different type, which is a bad thing for many applications." Though tedious methods exist to separate the different types, "the dream of this business is to create nanotubes in one type, or at least in some narrow distribution," Yakobson said. That is the focus of future research.

Tim Palucka